

Technical Data Sheet

Opto Interrupter

ITR9803

■ Features

- Fast response time
- High analytic
- Peak wavelength $\lambda_p=940\text{nm}$
- High sensitivity
- Pb free
- This product itself will remain within RoHS compliant version.

■ Descriptions

The ITR9803 consist of an infrared emitting diode and an NPN silicon phototransistor, encased side-by-side on converging optical axis in a black thermoplastic housing .

The phototransistor receives radiation from the IR LED only .This is the normal situation. But when an object is in between , phototransistor could not receives the radiation. For additional component information , please refer to IR and PT.

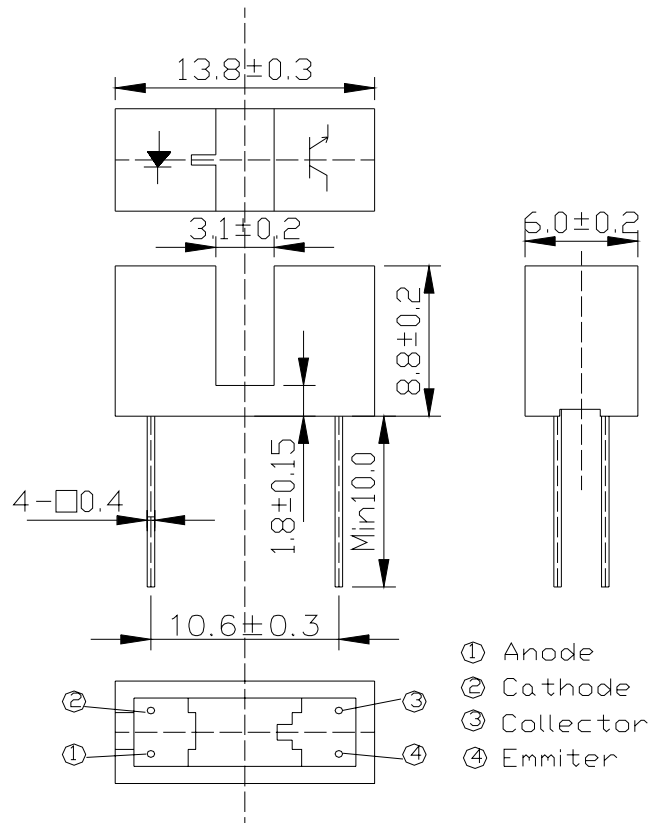
■ Applications

- Mouse Copier
- Switch Scanner
- Floppy disk driver
- Non-contact Switching
- For Direct Board

■ Device Selection Guide

Device No.	Chip Material	LENS COLOR
IR	GaAlAs	Pink
PT	Silicon	Water clear

■ Package Dimensions



Notes:

- 1.All dimensions are in millimeters
- 2.Tolerances unless dimensions $\pm 0.25\text{mm}$
- 3.Lead spacing is measured where the lead emerge from the package
- 4.Above specification may be changed without notice. EVERLIGHT will reserve authority on material change for above specification
- 5.These specification sheets include materials protected under copyright of EVERLIGHT corporation . Please don't reproduce or cause anyone to reproduce them without EVERLIGHT's consent
- 6.When using this product , please observe the absolute maximum ratings and the instructions for use outlined in these specification sheets. EVERIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.

Absolute Maximum Ratings (Ta=25°C)

Parameter		Symbol	Ratings	Unit
Input	Power Dissipation at(or below) 25°C Free Air Temperature	P _D	75	mW
	Reverse Voltage	V _R	5	V
	Forward Current	I _F	50	mA
	Peak Forward Current (*1) Pulse width ≤ 100μs, Duty cycle=1%	I _{FP}	1	A
Output	Collector Power Dissipation	P _C	75	mW
	Collector Current	I _C	20	mA
	Collector-Emitter Voltage	B V _{CEO}	30	V
	Emitter-Collector Voltage	B V _{ECO}	5	V
Operating Temperature		T _{opr}	-25~+85	°C
Storage Temperature		T _{stg}	-40~+100	°C
Lead Soldering Temperature (*2) (1/16 inch form body for 5 seconds)		T _{sol}	260	°C

(*1) $t_w=100 \mu \text{ sec.}$, $T=10 \text{ msec.}$ (*2) $t=5 \text{ Sec}$

Electro-Optical Characteristics (Ta=25°C)

Parameter		Symbol	Min.	Typ.	Max.	Unit	Conditions
Input	Forward Voltage	V _{FI}	---	1.2	1.6	V	I _F =20mA
	Reverse Current	I _R	---	---	10	μA	V _R =5V
	Peak Wavelength	λ _p	---	940	---	nm	I _F =20mA
	View Angle	2θ _{1/2}	---	60	---	Deg	I _F =20mA
Output	Dark Current	I _{CEO}	---	---	100	nA	V _{CE} =20V, Ee=0mW/cm ²
	C-E Saturation Voltage	V _{CE(sat)}	---	---	0.4	V	I _C =2mA ,Ee=1mW/cm ²
Transfer Characteristics	Collect Current	I _{C(ON)}	0.5	---	---	mA	V _{CE} =5V I _F =20mA
	Rise time	t _r	---	15	---	μsec	V _{CE} =5V I _C =1mA R _L =1KΩ
	Fall time	t _f	---	15	---	μsec	

Typical Electrical/Optical/Characteristics Curves for IR

Fig.1 Forward Current vs.

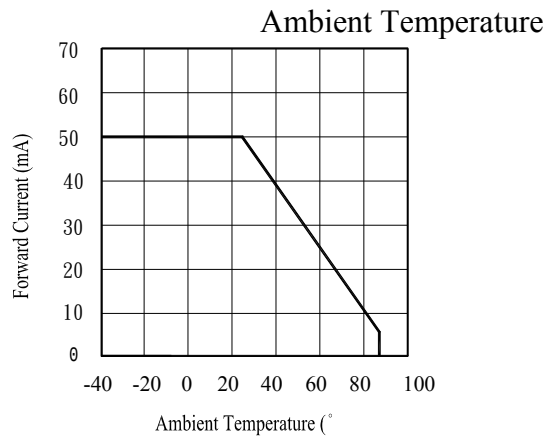


Fig.2 Spectral Distribution vs.

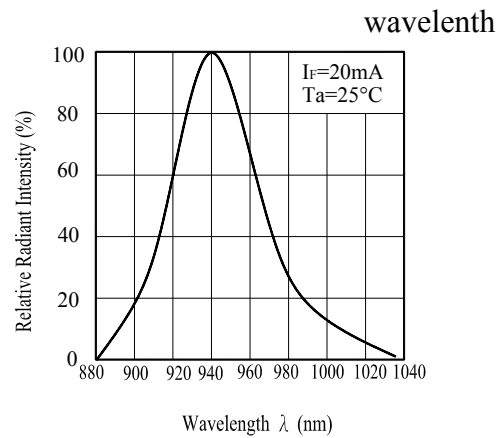


Fig.3 Relative Intensity vs.

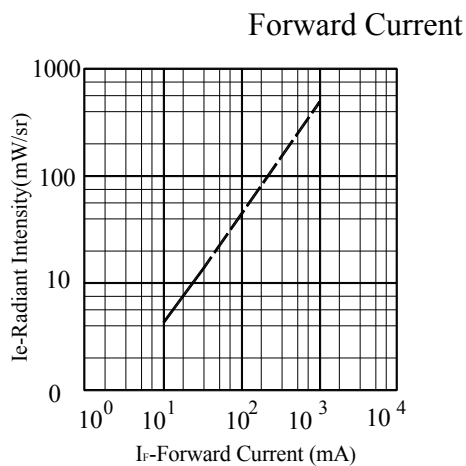
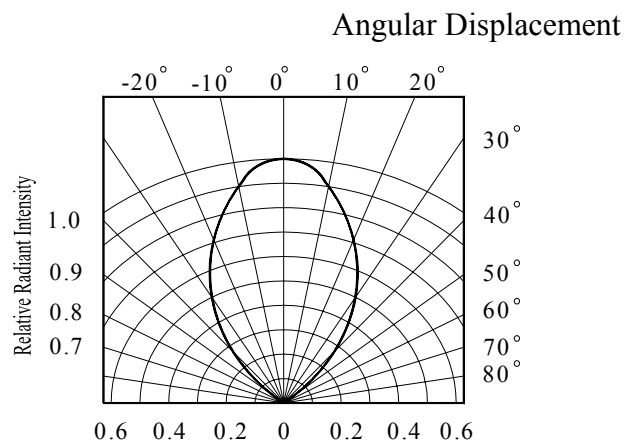


Fig.4 Relative Radiant Intensity vs.



Typical Electrical/Optical/Characteristics Curves for PT

Fig.1 Collector Power Dissipation vs. Ambient Temperature

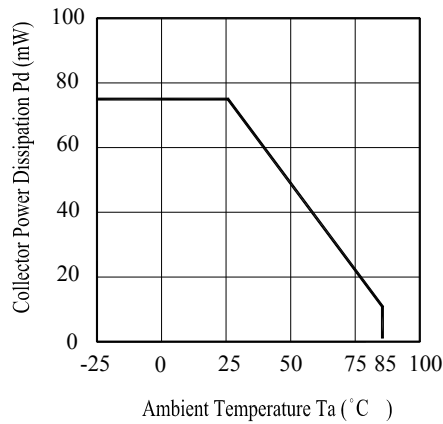


Fig.2 Spectral Sensitivity vs. Wavelength

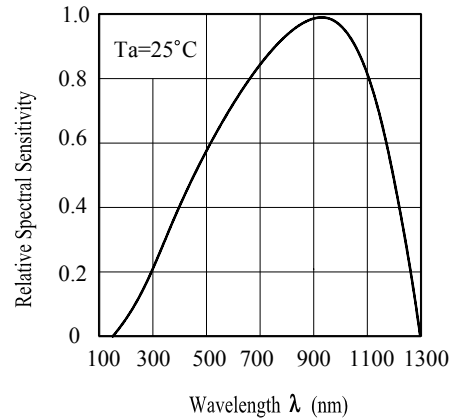


Fig.3 Relative Collector Current vs. Ambient Temperature

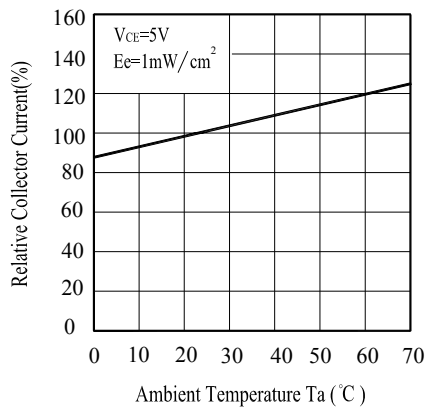


Fig.4 Collector Current vs. Irradiance

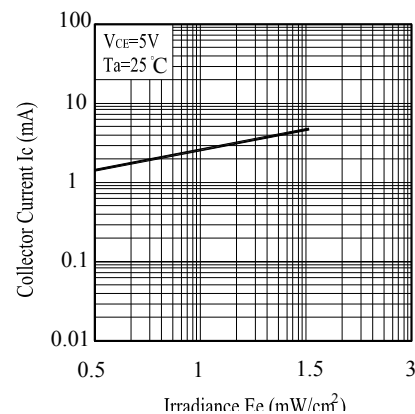


Fig.5 Collector Dark Current vs. Ambient Temperature

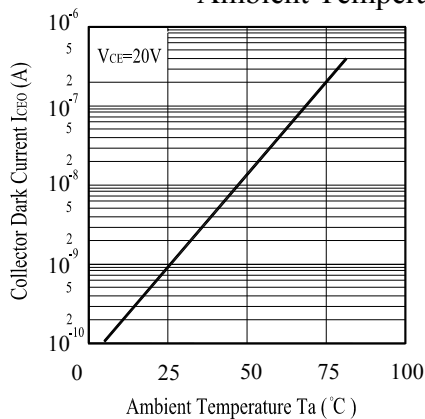
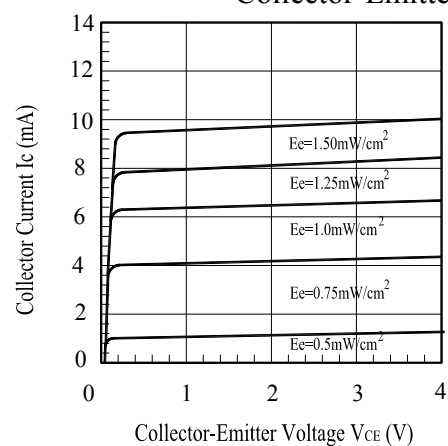


Fig.6 Collector Current vs. Collector-Emitter Voltage



Reliability Test Item And Condition

The reliability of products shall be satisfied with items listed below.

Confidence level : 90%

LTPD : 10%

NO.	Item	Test Condition	Test Hours/ Cycle	Sample Size	Failure Judgement Criteria	Ac/Re
1	Solder Heat	TEMP : 260°C ± 5 °C	5 sec	22 PCs	Attenuation of Light Current value>20%	0/1
2	Temperature Cycle	H : +100°C 15 mins ↕ 5 min L : -40°C 15 min	300 cycle	22 PCs		0/1
3	Thermal Shock	H : +100°C 5 min ↕ 10 sec L : -10°C 5 min	300 cycle	22 PCs		0/1
4	High Temperature Storage	TEMP. : +100°C	1000 hrs	22 PCs		0/1
5	Low Temperature Storage	TEMP. : -40°C	1000 hrs	22 PCs		0/1
6	DC Operating Life	V _{CE} =5V I _F =20mA	1000 hrs	22 PCs		0/1
7	High Temperature / High Humidity	85°C / 85% R.H.	1000 hrs	22 PCs		0/1

Packing Quantity Specification

1. 120PCS/1Plate,5Plates/1Box, 10Boxes/1Carton

Label Form Specification

	EVERLIGHT	
CPN: P/N:		
	RoHS	
ITR9803		
QTY:	CAT:	
	HUE:	
LOT NO:	REF:	
		
Reference		
		

CPN: Customer's Production Number

P/N : Production Number

QTY: Packing Quantity

CAT: Ranks

HUE: Peak Wavelength

REF: Reference

LOT No: Lot Number

X: Month

Reference: Identify Label Number

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